Technical Data Data Sheet 4957, Rev.-

# SILICON SCHOTTKY RECTIFIER DIE Very Low Forward Voltage Drop (150 °C T<sub>J</sub> Operation)

### **Applications:**

Switching Power Supply · Converters · Free-Wheeling Diodes · Polarity Protection Diode

## Features:

- Soft Reverse Recovery at Low and High Temperature
- Very Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics
- Electrically / Mechanically Stable during and after Packaging

### Maximum Ratings<sup>(1)</sup>:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	$V_{RWM}$	-	45	V
Max. Average Forward Current	I <sub>F(AV)</sub>	50% duty cycle, rectangular wave form	3	A
Max. Peak One Cycle Non- Repetitive Surge Current	I <sub>FSM</sub>	8.3 ms, half Sine wave	55	A
Non-Repetitive Avalanche Energy	E <sub>AS</sub>	$T_J = 25 \text{ °C}, I_{AS} = 1.3 \text{ A},$ L = 10 mH	8.6	mJ
Repetitive Avalanche Current	I <sub>AR</sub>	$I_{AS}$ decay linearly to 0 in 1 µs f limited by T <sub>J</sub> max V <sub>A</sub> =1.5V <sub>R</sub>	1.3	A
Max. Junction Temperature	$T_J$	-	-65 to +150	°C
Max. Storage Temperature	$T_{stg}$	-	-65 to +150	О°

## **Electrical Characteristics**<sup>(1)</sup>:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V <sub>F1</sub>	@ 3A, Pulse, T <sub>J</sub> = 25 °C	0.56	V
	$V_{F2}$	@ 3A, Pulse, T <sub>J</sub> = 125 °C	0.51	V
Max. Reverse Current	I <sub>R1</sub>	$@V_R = 45V$ , Pulse,	300	μA
		$T_J = 25 \ ^{\circ}C$		
	I <sub>R2</sub>	$@V_{R} = 45V, Pulse,$	14	mA
		T <sub>J</sub> = 125 °C		
Max. Junction Capacitance	C <sub>T</sub>	$@V_{R} = 5V, T_{C} = 25 \ ^{\circ}C$	160	pF
		f <sub>SIG</sub> = 1MHz,		
		$V_{SIG} = 50 \text{mV} (\text{p-p})$		

(1) in SHD package

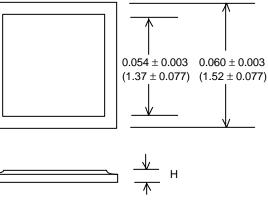
World Wide Web Site - http://www.sensitron.com • E-Mail Address - sales@sensitron.com •

## SEMICONDUCTOR

## SD060SA45A/B

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Mechanical Dimensions: In Inches / mm

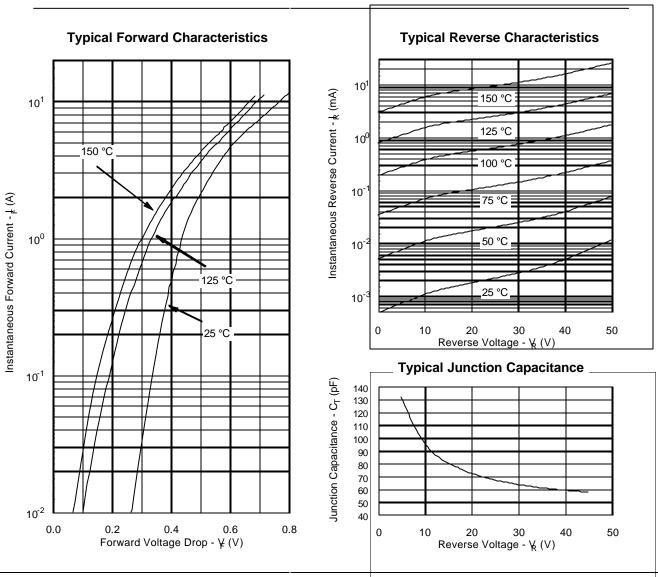


Bottom side metalization Ag - 30 kÅ minimum.

Top side metalization AI - 25 kÅ minimum or Ag - 30 kÅ minimum.

Bottom side is cathode, top side is anode.

Dimension H =  $0.0105 \pm 0.001$  (0.27  $\pm 0.026$ ) for Al top; Dimension H =  $0.0155 \pm 0.001$  (0.39  $\pm 0.026$ ) for Ag top.





### **TECHNICAL DATA**

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